

## Features

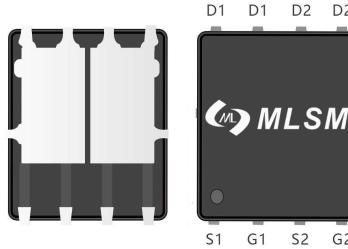
- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Green Device Available

## Application

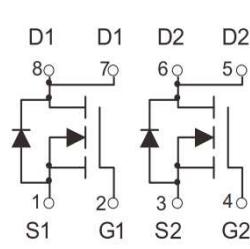
- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

## Product Summary

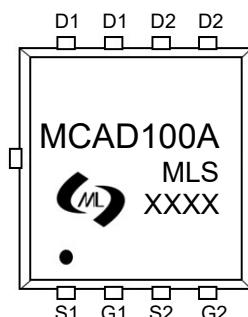
$V_{DS}$	$R_{DS(ON)} \text{ MAX}$	$I_D \text{ MAX}$
30V	5mΩ@10V	100A
	7mΩ@4.5V	



PDFN5X6-8L view



Schematic diagram



Marking and pin assignment

MCAD100A : Device code  
XXXX : Code


Halogen-Free

## Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit	
<b>Common Ratings (TC=25°C Unless Otherwise Noted)</b>				
$V_{DS}$	Drain-Source Breakdown Voltage	30	V	
$V_{GS}$	Gate-Source Voltage	±20	V	
$T_J$	Maximum Junction Temperature	150	°C	
$T_{STG}$	Storage Temperature Range	-55 to 150	°C	
$I_S$	Diode Continuous Forward Current	100	A	
<b>Mounted on Large Heat Sink</b>				
$I_{DM}$	Pulse Drain Current Tested	Tc=25°C	400	A
$I_D$	Continuous Drain Current	Tc=25°C	100	A
$P_D$	Maximum Power Dissipation	Tc=25°C	65	W
$R_{QJA}$	Thermal Resistance Junction-Ambient		83	°C/W

## Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MCAD100A	PDFN5X6-8L	MCAD100A	5,000	10,000	70,000	13"reel

**Electrical Characteristics (TJ=25°C unless otherwise noted)**

Symbol	Parameter	Condition	Min	Typ	Max	Unit
<b>Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)</b>						
BV <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V, I <sub>D</sub> =250μA	30	--	--	V
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> =30V, V <sub>GS</sub> =0V	--	--	1	μA
I <sub>GSS</sub>	Gate-Body Leakage Current	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	--	--	±100	nA
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250μA	1.0	1.5	2.5	V
R <sub>DS(on)</sub>	Drain-Source On-State Resistance	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	--	3.3	5	mΩ
		V <sub>GS</sub> =4.5V, I <sub>D</sub> =10A	--	5	7	mΩ

**Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)**

C <sub>ISS</sub>	Input Capacitance	V <sub>DS</sub> =15V, V <sub>GS</sub> =0V, f=1MHz	--	1700	--	pF
C <sub>OSS</sub>	Output Capacitance		--	320	--	pF
C <sub>RSS</sub>	Reverse Transfer Capacitance		--	300	--	pF

**Switching Characteristics**

Q <sub>g</sub>	Total Gate Charge	V <sub>DS</sub> =15V, I <sub>D</sub> =15A, V <sub>GS</sub> =10V	--	45	--	nC
Q <sub>gs</sub>	Gate Source Charge		--	3	--	nC
Q <sub>gd</sub>	Gate Drain Charge		--	15	--	nC
t <sub>d(on)</sub>	Turn-on Delay Time		--	21	--	nS
t <sub>r</sub>	Turn-on Rise Time	V <sub>DS</sub> =15V, I <sub>D</sub> =15A, V <sub>GS</sub> =10V, R <sub>G</sub> =3Ω	--	32	--	nS
t <sub>d(off)</sub>	Turn-Off Delay Time		--	60	--	nS
t <sub>f</sub>	Turn-Off Fall Time		--	34	--	nS

**Source- Drain Diode Characteristics**

V <sub>SD</sub>	Forward on voltage	T <sub>j</sub> =25°C, I <sub>s</sub> =10A	--	--	1.2	V
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### Typical Operating Characteristics

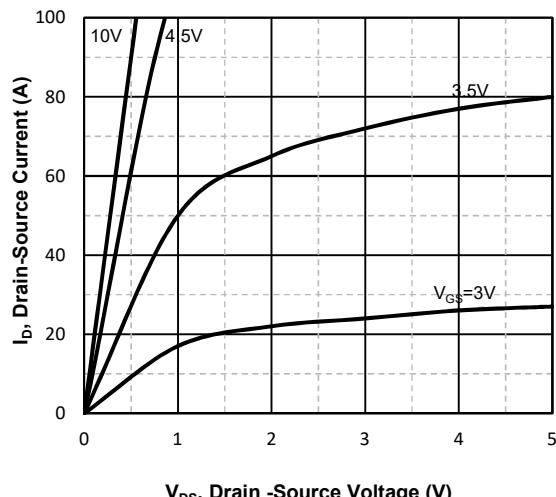


Fig1. Typical Output Characteristics

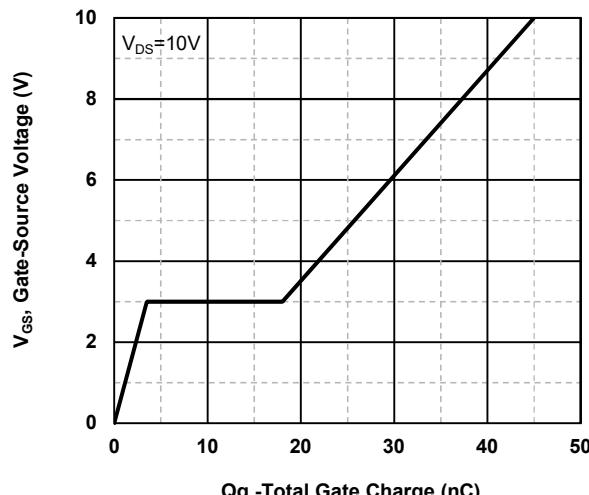


Fig2. Typical Gate Charge Vs.Gate-Source Voltage

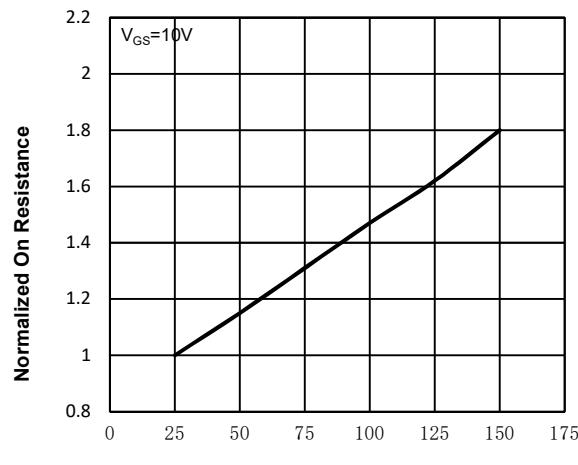


Fig3. Normalized On-Resistance Vs. Temperature

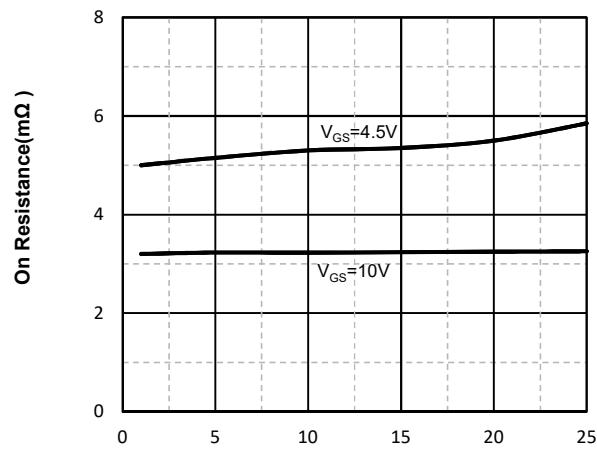


Fig4. On-Resistance Vs. Drain-Source Current

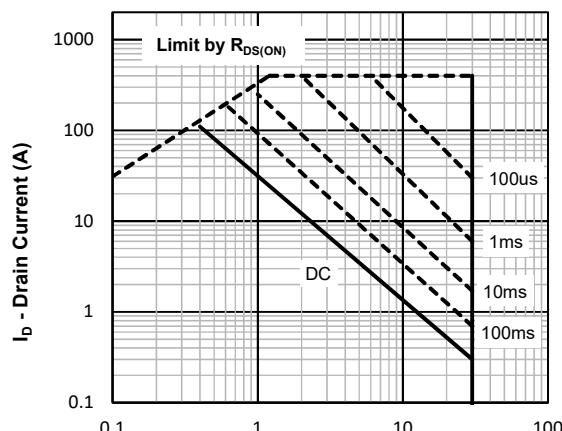


Fig5. Maximum Safe Operating Area

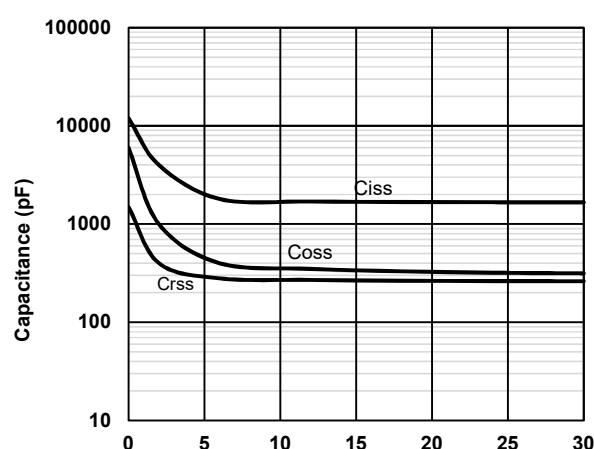
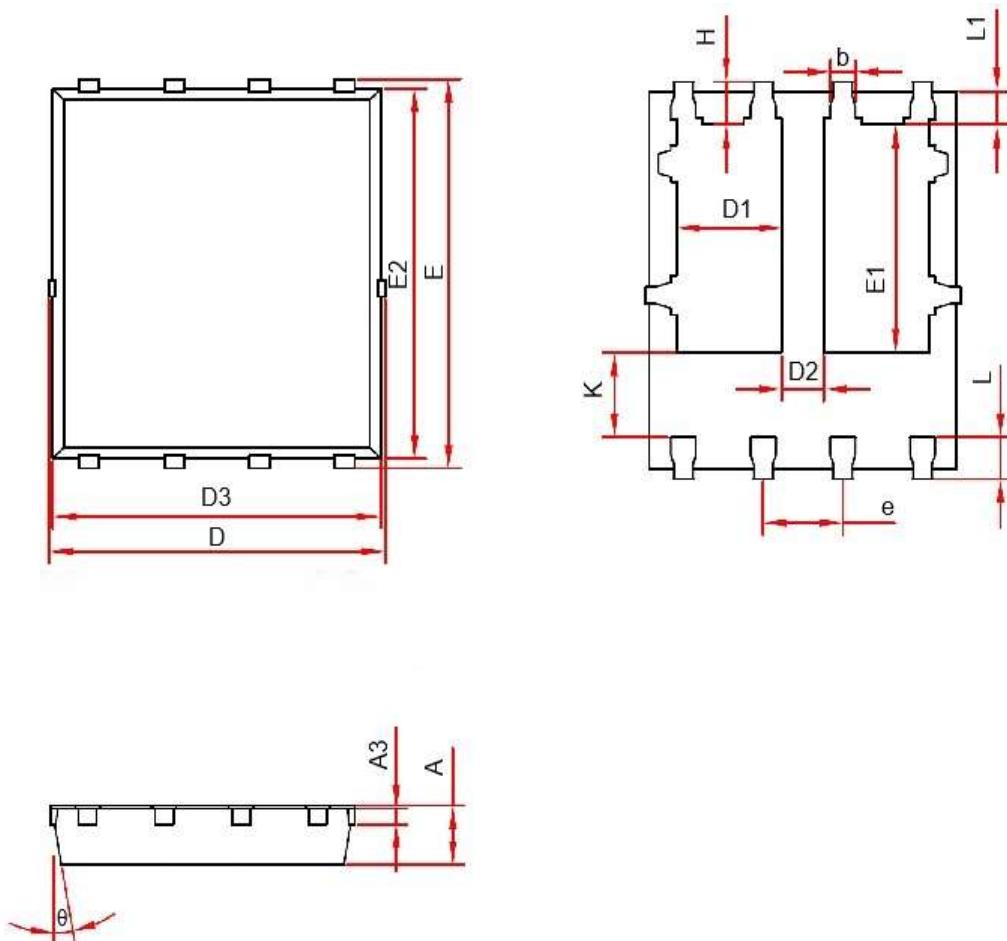


Fig6 Typical Capacitance Vs.Drain-Source Voltage

**PDFN5X6-8L Package information**


Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	0.950	1.050	0.035	0.039
A3	0.254REF.		0.010REF.	
D	4.950	5.050	0.196	0.200
E	5.950	6.050	0.235	0.239
D1	1.470	1.870	0.058	0.074
D2	0.470	0.870	0.019	0.034
E1	3.510	3.610	0.139	0.143
D3	4.850	4.950	0.192	0.196
E2	5.700	5.800	0.225	0.229
k	1.190	1.390	0.047	0.055
b	0.300	0.400	0.012	0.016
e	1.270TYP.		0.050TYP.	
L	0.559	0.711	0.022	0.028
L1	0.424	0.576	0.017	0.023
H	0.574	0.726	0.023	0.029
θ	10°	12°	10°	12°